







J308, J309, J310 N-Channel JFET

Features

- InterFET N0072L Geometry
- Low Noise: 2 nV/VHz Typical
- Low Ciss: 4pF Typical
- · RoHS Compliant
- SMT, TH, and Bare Die Package options.

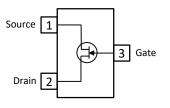
Applications

- Mixers
- Oscillators
- · VHF/UHF Amplifiers

Description

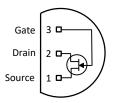
The -25V InterFET J308, J309, and J310 are targeted for higher gain VHF amplifiers, mixers, and oscillators. Gate leakages are typically less than 10pA at room temperatures.

SOT23 Top View





TO-92 Bottom View





Product Summary

	Parameters	J308 Min	J309 Min	J310 Min	Unit
BV _{GSS}	Gate to Source Breakdown Voltage	-25	-25	-25	V
I _{DSS}	Drain to Source Saturation Current	12	12	24	mA
V _{GS(off)}	Gate to Source Cutoff Voltage	-1	-1	-2	V
GFS	Forward Transconductance	8	10	8	mS

Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
J308; J309; J310	Through-Hole	TO-92	Bulk
SMPJ308; SMPJ309; SMPJ310	Surface Mount	SOT23	Bulk
	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMPJ308TR; SMPJ309TR; SMPJ310TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
J308COT; J309COT; J310COT	Chip Orientated Tray (COT Waffle Pack)	COT	400/Waffle Pack
J308CFT; J309CFT; J310CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack



Disclaimer: It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.









Electrical Characteristics

Maximum Ratings (@ T_A = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
V_{RGS}	Reverse Gate Source and Gate Drain Voltage	-25	V
I _{FG}	Continuous Forward Gate Current	10	mA
P_D	Continuous Device Power Dissipation	360	mW
Р	Power Derating	3.27	mW/°C
Tı	Operating Junction Temperature	-55 to 125	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Static Characteristics (@ TA = 25°C, Unless otherwise specified)

			J308		J309			J310				
	Parameters	Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
V _{(BR)GSS}	Gate to Source Breakdown Voltage	$V_{DS} = 0V$, $I_{G} = -1\mu A$	-25			-25			-25			V
I _{GSS}	Gate to Source Reverse Current	$V_{GS} = -15V$, $V_{DS} = 0V$, $T_A = 25$ °C $V_{GS} = -15V$, $V_{DS} = 0V$, $T_A = 125$ °C			-1 -1			-1 -1			-1 -1	nA μA
V _{GS(OFF)}	Gate to Source Cutoff Voltage	V _{DS} = 10V, I _D = 1nA	-1		-6.5	-1		-4	-2		-6.5	V
V _{GS(F)}	Gate to Source Forward Voltage	$V_{DS} = 0V$, $I_G = 1mA$			1			1			1	V
I _{DSS}	Drain to Source Saturation Current	$V_{GS} = 0V$, $V_{DS} = 10V$ (Pulsed)	12		60	12		30	24		60	mA

Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

			J308		J309			J310				
	Parameters	Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
GFS	Forward Transconductance	V _{DS} = 10V, I _D = 10mA, f = 1kHz	8	17		10	17		8	17		mS
Gos	Output Conductance	V _{DS} = 10V, I _D = 10mA, f = 1kHz			250			250			250	μS
G _{FG}	Gate Forward Transconductance	V _{DS} = 10V, I _D = 10mA, f = 1kHz		13			13			1.2		mS
G _{OG}	Gate Output Transconductance	V _{DS} = 10V, I _D = 10mA, f = 1kHz		150			100			150		μS
C _{dg}	Drain Capacitance	$V_{DS} = 0V$, $V_{GS} = -10V$, $f = 1MHz$		1.8	2.5		1.8	2.5		1.8	2.5	pF
Cgs	Source Capacitance	V _{DS} = 0V, V _{GS} = -10V, f = 1MHz		4	5		4	5		4	5	pF
e _n	Noise Voltage	V _{DS} = 10V, I _D = 10mA, f = 100kHz			10			10			10	nV/√Hz
NF	Noise Figure	$V_{DS} = 15V$, $I_D = 10mA$, $f = 105MHz$ $V_{DS} = 15V$, $I_D = 10mA$, $f = 450MHz$		1.5 2.7			1.5 2.7			1.5 2.7		dB



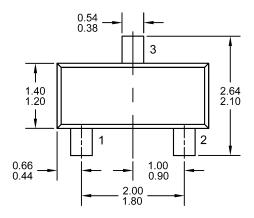


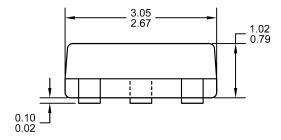


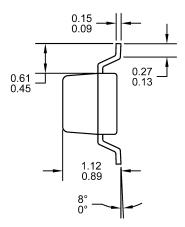


SOT23 (TO-236AB) Mechanical and Layout Data

Package Outline Data

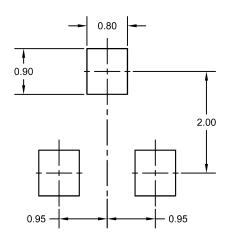






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

Suggested Pad Layout



- L. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.



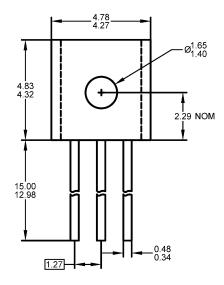


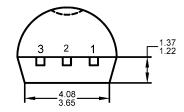


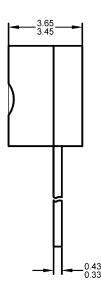


TO-92 Mechanical and Layout Data

Package Outline Data

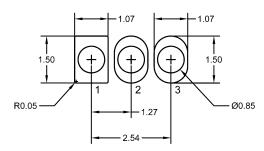






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.